

isc Silicon NPN Power Transistor

2SD2125

DESCRIPTION

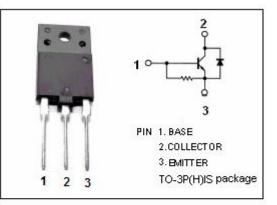
- High Breakdown Voltage-
 - : V_{CBO}= 1500V (Min)
- High Switching Speed
- Low Saturation Voltage
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

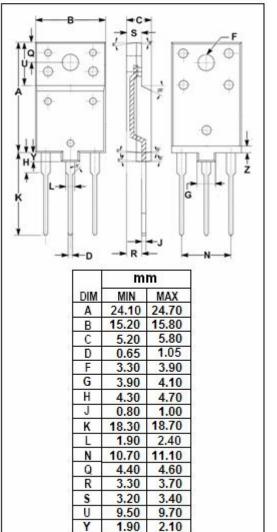
APPLICATIONS

Designed for color TV horizontal output applications

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	1500	v
V _{CEO}	Collector-Emitter Voltage	600	v
V _{EBO}	Emitter-Base Voltage	5	v
lc	Collector Current-Continuous	6	A
Ісм	Collector Current-Peak	10	A
I _B	Base Current- Continuous	3	А
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	50	w
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

ABSOLUTE MAXIMUM RATINGS(T_a=25°C)





Z

1.40

1.60



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ELECTRICAL CHARACTERISTICS

$T_{c}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 200mA; I _C = 0	5			V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 5Α; I _B = 1Α			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			10	μA
hfe-1	DC Current Gain	I _C = 1A; V _{CE} = 5V	8		20	
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 5V	5			
V _{ECF}	C-E Diode Forward Voltage	I⊧= 6A			2.0	V
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V		3		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} =1.0MHz		165		pF
tr	Fall Time	I _{CP} = 5A, I _{B1(end)} = 1A			0.5	μ S

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